



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: Yasuhiko NOMURA et al.

Serial No.: 09/666,553

Group Art Unit: 2828

Examiner: Quyen Phan Leung

Filed: September 21, 2000

FOR: SEMICONDUCTOR LIGHT EMITTING DEVICE

AMENDMENT UNDER 37 C.F.R. §1.111

Commissioner for Patents
Washington, D.C. 20231

Date: August 5, 2002

Sir:

In response to the Office Action dated March 5, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

Please amend claims 17-20 as follows:

17. (Amended) A semiconductor light emitting device comprising:
- an emission layer composed of a nitride-based semiconductor;
 - a cladding layer, formed on said emission layer, composed of a nitride-based semiconductor having a flat portion and a projection portion located on said flat portion; and
 - a layer of nitride-based semiconductor formed on said projection portion, wherein
 - said projection portion of said cladding layer and said layer formed on said projection portion form a ridge portion, and
 - said ridge portion has a step formed between said projection portion of said cladding layer and said layer formed on said projection portion;

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